## 2SD2177

## Silicon NPN epitaxial planer type

For low-frequency output amplification Complementary to 2SB1434

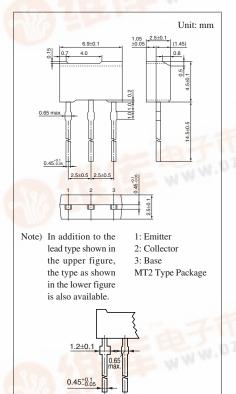
#### ■ Features

- Low collector to emitter saturation voltage V<sub>CE(sat)</sub>
- Ccomplementary pair with 2SB1434
- Allowing supply with the radial taping

## ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Collector to base voltage	V <sub>CBO</sub>	50	V
Collector to emitter voltage	V <sub>CEO</sub>	50	V
Emitter to base voltage	V <sub>EBO</sub>	5	V
Peak collector current	$I_{CP}$	3	A
Collector current	$I_{C}$	2	A
Collector power dissipation *	$P_{\rm C}$	1	W
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

Note) \*: Printed circuit board: Copper foil area of 1 cm<sup>2</sup> or more, and the board thickness of 1.7 mm for the collector portion



(HW Type)

#### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff current	$I_{CBO}$	$V_{CB} = 20 \text{ V}, I_{E} = 0$			0.1	μΑ
Collector to base voltage	$V_{CBO}$	$I_C = 10 \ \mu A, I_E = 0$	50		- 4	V
Collector to emitter voltage	$V_{CEO}$	$I_C = 1 \text{ mA}, I_B = 0$	50			V
Emitter to base voltage	$V_{\mathrm{EBO}}$	$I_E = 10 \ \mu A, I_C = 0$	5			V
Forward current transfer ratio *1	h <sub>FE1</sub> *2	$V_{CE} = 2 \text{ V, } I_{C} = 200 \text{ mA}$	120		340	
	h <sub>FE2</sub>	$V_{CE} = 2 \text{ V}, I_C = 1 \text{ A}$	80			
Collector to emitter saturation voltage *1	V <sub>CE(sat)</sub>	$I_C = 1 \text{ A}, I_B = 50 \text{ mA}$		0.15	0.3	V
Base to emitter saturation voltage *1	V <sub>BE(sat)</sub>	$I_C = 1 \text{ A}, I_B = 50 \text{ mA}$		0.85	1.2	V
Transition frequency	$f_T$	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		110		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		23	35	pF

Note) \*1: Pulse measurement

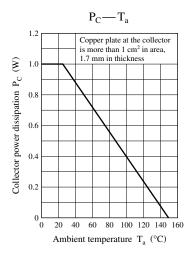
\*2: Rank classification

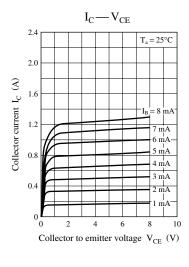
Rank	R	S	No-rank
PDF	120 to 240	170 to 340	120 to 340

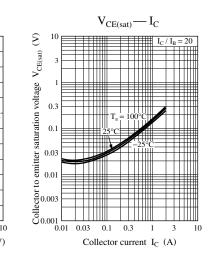
Product of no-rank is not classified and have no indication for rank.

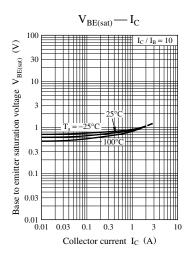
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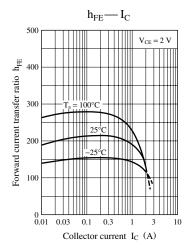
2SD2177 Transistors

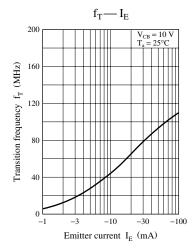


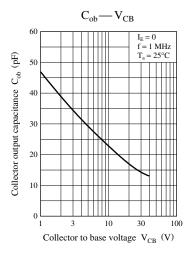












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